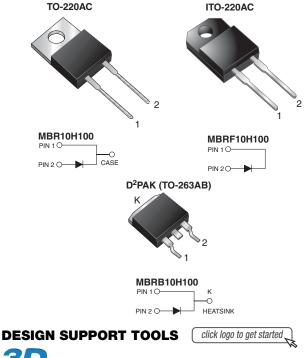


MBR10H100, MBRF10H100, MBRB10H100

Vishay General Semiconductor

High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance





PRIMARY CHARACTERISTICS						
I _{F(AV)}	10 A					
V _{RRM} 100 V						
I _{FSM}	250 A					
V _F	0.64 V					
I _R	4.5 µA					
T _J max.	175 °C					
Package	TO-220AC, ITO-220AC, D ² PAK (TO-263AI					
Circuit configurations Single						

FEATURES

- Power pack
- Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- · High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AC and ITO-220AC package)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: TO-220AC, ITO-220AC, D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted)					
PARAMETER		MBR10H100	UNIT		
Maximum repetitive peak reverse voltage	V _{RRM}	100			
Working peak reverse voltage	V _{RWM}	100	V		
Maximum DC blocking voltage	V _{DC}	100			
Maximum average forward rectified current	I _{F(AV)}	10			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	250	А		
Peak repetitive reverse current at $t_p = 2.0 \ \mu s$, 1 kHz	I _{RRM}	0.5			
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs		
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +175	°C		
Isolation voltage (ITO-220AC only) from terminal to heatsink t = 1 min	V _{AC}	1500	V		

Revision: 08-Jun-2018

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ELECTRICAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CO	ONDITIONS	VALUE	UNIT	
Maximum instantaneous forward voltage	V _F ⁽¹⁾	I _F = 10 A	T _C = 25 °C	0.77	v	
		I _F = 10 A	T _C = 125 °C	0.64		
		I _F = 20 A	T _C = 25 °C	0.88		
		I _F = 20 A	T _C = 125 °C	0.73]	
Maximum reverse current	L (2)	Rated V _R	T _J = 25 °C	4.5	μA	
	I _R ⁽²⁾		T _J = 125 °C	6.0	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance	$R_{ ext{ heta}JC}$	2.7	5.8	2.7	°C/W

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AC	MBR10H100-E3/45	1.80	45	50/tube	Tube	
ITO-220AC	MBRF10H100-E3/45	1.94	45	50/tube	Tube	
TO-263AB	MBRB10H100-E3/45	1.33	45	50/tube	Tube	
TO-263AB	MBRB10H100-E3/81	1.33	81	800/reel	Tape and reel	



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RATINGS AND CHARACTERISTICS CURVES ($T_C = 25$ °C unless otherwise noted)

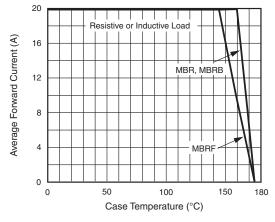


Fig. 1 - Forward Current Derating Curve

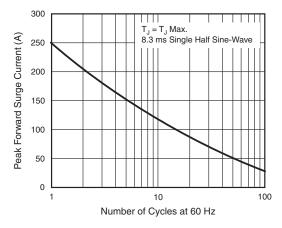


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

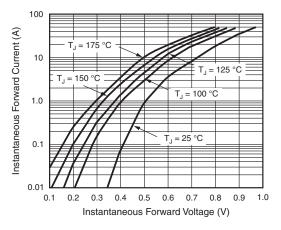


Fig. 3 - Typical Instantaneous Forward Characteristics

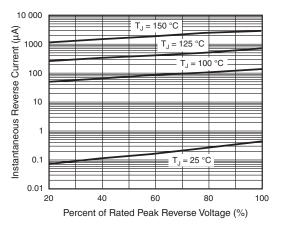


Fig. 4 - Typical Reverse Characteristics

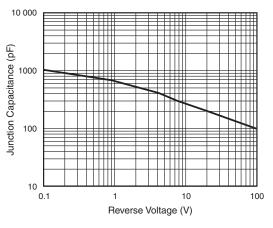


Fig. 5 - Typical Junction Capacitance

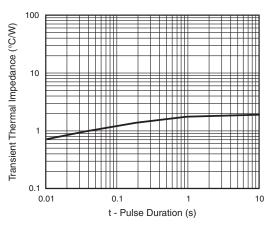


Fig. 6 - Typical Transient Thermal Impedance

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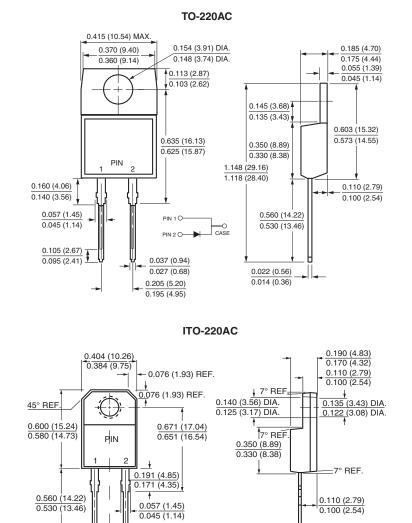
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



D²PAK (TO-263AB)

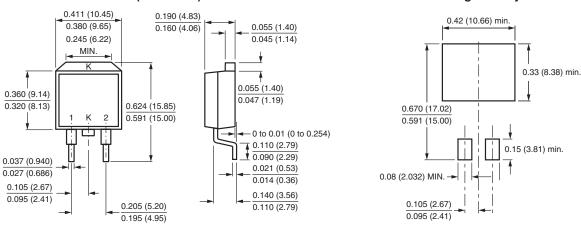
0.025 (0.64)

0.015 (0.38)



0.028 (0.71)

0.020 (0.51)



0.035 (0.89)

0.025 (0.64) 0.205 (5.21)

0.195 (4.95)

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